

RA20 4800A (Outline Drawing)



RA20 4800A General Purpose Rectifier
4800 Amperes Average, 1200 Volts

Description:

Powerex General Purpose Rectifiers are designed for high blocking voltage capability with low forward voltage to minimize conduction losses. The hermetic Pow-R-Disc devices can be mounted using commercially available clamps and heatsinks.

Features:

- Low Forward Voltage
- Low Thermal Impedance
- Hermetic Packaging
- Excellent Surge and I^2t Ratings

Applications:

- Power Supplies
- Motor Control
- Free Wheeling Diode
- Battery Chargers
- Resistance Welding

Ordering Information:

Select the complete ten digit module part number from the table below.
Example: RA201248XX is a 1200V 4800 A General Purpose Rectifier

Type	Voltage V_{RRM} (Volts)	Current $I_{T(av)}$ (A)	Typical Recovery Time t_{RR} (μ sec)
RA20	06 through 12	48	XX
	600V through 1200V	4800A	16 μ sec typical



**RA20
4800A**

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**General Purpose Rectifier
4800 Amperes Average
1200 Volts**

Absolute Maximum Ratings

Characteristics	Symbol	Units
Non-Repetitive Transient Peak Reverse Blocking Voltage	V_{RSM} $V_{RRM} + 200V$	Volts
RMS Forward Current, $T_C = 98^\circ C$	$I_{F(RMS)}$	7535 Amperes
Average Current 180° Sine Wave, $T_C = 98^\circ C$	$I_{F(AV)}$	4800 Amperes
RMS Forward Current, $T_C = 55^\circ C$	$I_{F(RMS)}$	9420 Amperes
Average Current 180° Sine Wave, $T_C = 55^\circ C$	$I_{F(AV)}$	6000 Amperes
Peak One Cycle Surge Forward Current (Non-Repetitive) 60 Hz	I_{FSM}	49000 Amperes
Peak One Cycle Surge Forward Current (Non-Repetitive) 50 Hz	I_{FSM}	44600 Amperes
3 Cycle Surge Current	I_{FSM}	39200 Amperes
10 Cycle Surge Current	I_{FSM}	30600 Amperes
I^2t (for Fusing) for One Cycle, 60 Hz	I^2t	10.0×10^6 A ² sec
Maximum I^2t of Package ($t = 8.3$ msec)	I^2t	125×10^6 A ² sec
Operating Temperature	T_J	-40 to +190 °C
Storage Temperature	T_{stg}	-40 to +200 °C
Approximate Weight		2.1 lb.
		950 G
Mounting Force		9000 to 11000 lb.
		4100 to 5000 kg.

Information presented is based upon manufacturers testing and projected capabilities.
This information is subject to change without notice.
The manufacturer makes no claim as to the suitability of use, reliability, capability,
or future availability of this product.

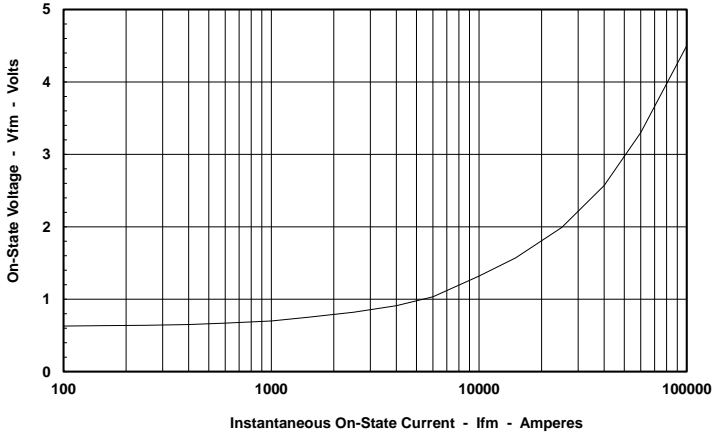
Electrical Characteristics, $T_J=25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Max.	Units
Repetitive Peak Reverse Leakage Current	I_{RRM}	$T_J=150^\circ\text{C}$, $V_R = V_{RRM}$		150	mA
Peak On-State Voltage	V_{FM}	$I_{FM}=3000\text{A}$, Duty Cycle < 0.1 %		1.05	V
Threshold Voltage, Low-level	$V_{(TO)1}$	$T_J = 190^\circ\text{C}$, $I = 15\%I_{F(AV)}$ to $\pi I_{F(AV)}$		0.65128	V
Slope Resistance, Low-level	r_{T1}			0.06315	$\text{m}\Omega$
Threshold Voltage, High-level	$V_{(TO)2}$	$T_J = 190^\circ\text{C}$, $I = \pi I_{F(AV)}$ to I_{FSM}		1.0168	V
Slope Resistance, High-level	r_{T2}			0.0383	$\text{m}\Omega$
V_{TM} Coefficients, Low-level		$T_J = 190^\circ\text{C}$, $I = 15\%I_{F(AV)}$ to $\pi I_{F(AV)}$	$A_1 =$	0.86976	
		$V_{FM} = A + B \ln I + C I + D \text{ Sqrt } I$	$B_1 =$	-0.05790	
			$C_1 =$	3.296E-05	
			$D_1 =$	0.006296	
V_{TM} Coefficients, High-level		$T_J = 190^\circ\text{C}$, $I = \pi I_{F(AV)}$ to I_{FSM}	$A_2 =$	0.18145	
		$V_{FM} = A + B \ln I + C I + D \text{ Sqrt } I$	$B_2 =$	0.064997	
			$C_2 =$	2.921E-05	
			$D_2 =$	0.002657	
Diode Reverse Recovery Time (Typical)	t_{rr}	$T_C = 25^\circ\text{C}$, $I_{FM} = 1500\text{A}$, $di_R/dt = -25\text{A}/\mu\text{s}$, $T_p = 190 \mu\text{s}$		16 (Typical)	μs

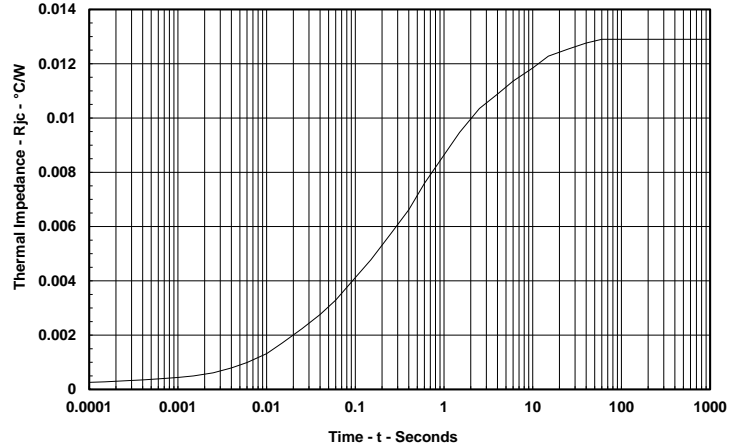
Thermal Characteristics

Maximum Thermal Resistance, Double Sided Cooling		Max.	Units
Junction-to-Case	$R_{\theta(J-C)}$	0.013	$^\circ\text{C}/\text{W}$
Case-to-Sink	$R_{\theta(C-S)}$	0.007	$^\circ\text{C}/\text{W}$

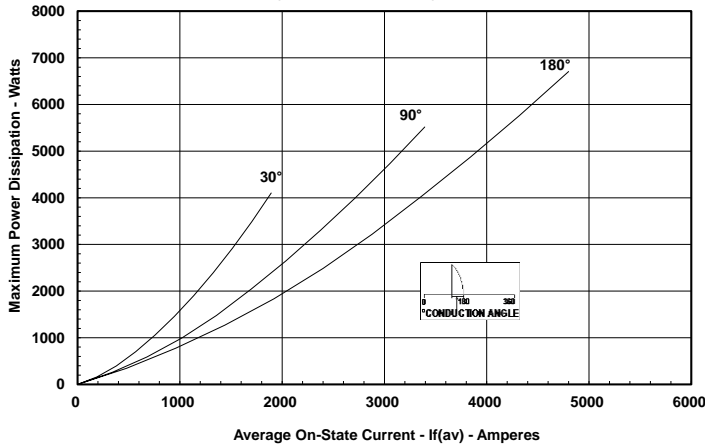
Maximum On-State Forward Voltage Drop
($T_j = 190^\circ\text{C}$)



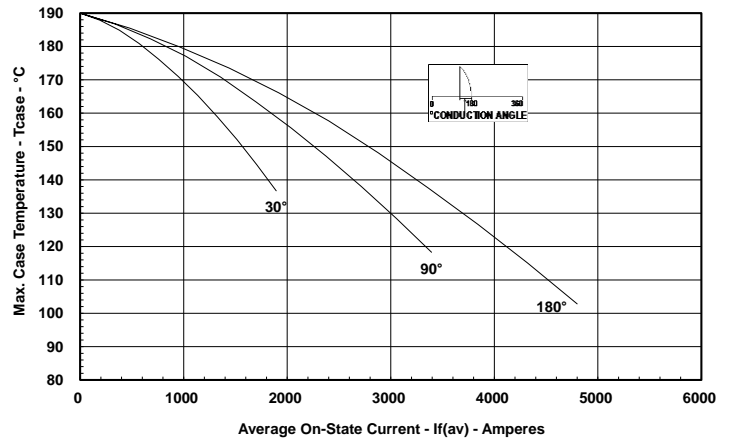
Maximum Transient Thermal Impedance
(Junction to Case)



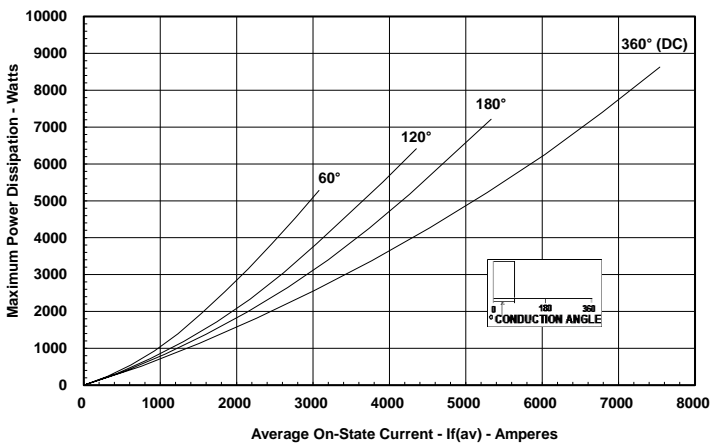
Maximum On-State Power Dissipation
(Sinusoidal Waveform)



Maximum Allowable Case Temperature
(Sinusoidal Waveform)



Maximum On-State Power Dissipation
(Rectangular Waveform)



Maximum Allowable Case Temperature
(Rectangular Waveform)

